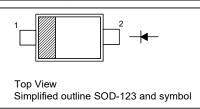
Silicon Epitaxial Planar Switching Diode

Features

- AEC-Q101 Qualified
- · High switching speed
- Low capacitance
- Low leakage current
- Halogen and Antimony Free(HAF), RoHS compliant

PINNING

PIN	DESCRIPTION		
1	Cathode		
2	Anode		



Absolute Maximum Ratings (T_a = 25°C)

Parameter		Symbol	Value	Unit
Repetitive Peak Reverse Voltage		V_{RRM}	100	V
Reverse Voltage	V _R 100		V	
Continuous Forward Current		I _F	215	mA
Repetitive Peak Forward Current	at t _p ≤ 0.5 ms	I _{FRM}	500	mA
Non-repetitive Peak Forward Surge Current	at $t_p = 1 s$ at $t_p = 1 ms$ at $t_p = 1 \mu s$	I _{FSM}	0.5 1 4	Α
Power Dissipation		P _D	400	mW
Junction Temperature		T _j	150	°C
Storage Temperature Range		T _{stg}	- 65 to + 150	°C

Thermal Characteristics

Parameter	Symbol	Max.	Unit
Thermal Resistance from Junction to Ambient 1)	$R_{ heta JA}$	313	°C/W

¹⁾ Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.



BAS16W1-AH

Characteristics at $T_a = 25$ °C

Parameter	Symbol	Min.	Max.	Unit
Reverse Breakdown Voltage at I _R = 10 μA	$V_{(BR)R}$	100	-	V
Forward Voltage at $I_F = 1 \text{ mA}$ at $I_F = 10 \text{ mA}$ at $I_F = 50 \text{ mA}$ at $I_F = 150 \text{ mA}$	V _F		0.715 0.855 1 1.25	V
Reverse Current at $V_R = 25 \text{ V}$ at $V_R = 80 \text{ V}$ at $V_R = 25 \text{ V}$, $T_j = 150^{\circ}\text{C}$ at $V_R = 80 \text{ V}$, $T_j = 150^{\circ}\text{C}$	I _R		30 0.5 30 50	nA A4 A4 A4
Diode Capacitance at $V_R = 0 V$, $f = 1 MHz$	C _d	-	1.5	pF
Reverse Recovery Time at I_F = 10 mA, I_{rr} = 0.1 X I_R , V_R = 6 V, R_L = 100 Ω	t _{rr}	-	4	ns



Electrical Characteristics Curves

Fig 1. Power Derating Curve

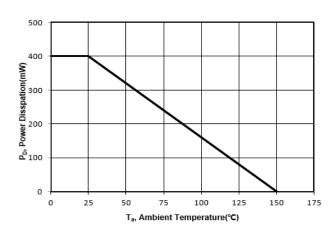


Fig 2. Capacitance Characteristics

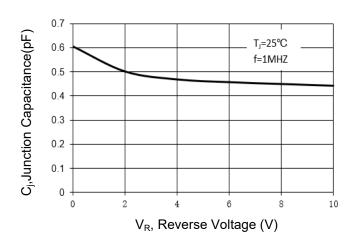


Fig 3. Reverse Characteristics

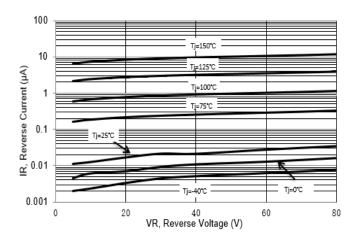
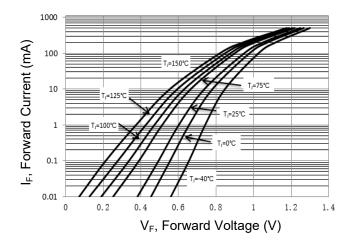


Fig 4. Forward Characteristics

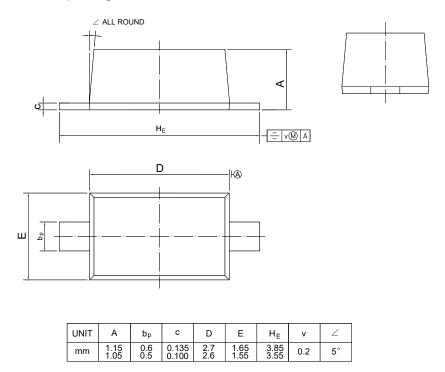




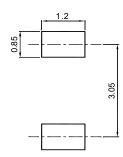
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123



Recommended Soldering Footprint



Packing information

r acking information								
	Package	Tape Width (mm)	Pitch		Reel Size		Per Reel Packing Quantity	
	rackage		mm	(inch)	mm	(inch)	rei Neel Fackling Qualitity	
	SOD-123	8	4 ± 0.1	0.157 ± 0.004	178	7	3,000	

Marking information

"W1" = Part No

"III" = Cathode line

" • "= HAF (Halogen and Antimony Free(HAF)

Font type: Arial



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